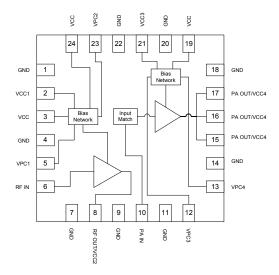


Applications

- 802.11a WLAN
- HiperLAN/2 WLAN
- U-NII fixed wireless equipment



Functional Block Diagram

Advanced RFSP5032

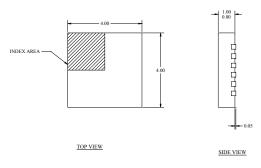
5.15-5.85 GHz U-NII Power Amplifier

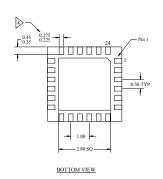
Product Description

The RFSP5032 power amplifier is a high-performance GaAs HBT IC designed for use in transmit applications in the 5.15-5.85 GHz frequency band. With a P1dB of 26 dBm, the device is ideal as a final stage for wireless LAN applications requiring high transmit linearity. The part demonstrates very low error vector magnitude (EVM) at the full 54 Mbps data rate for 802.11a. The input of the PA is matched to 50 ohms and the output can be easily matched for optimum linearity and power performance at the desired frequency of operation between 5.15 and 5.85 GHz. The part operates off a single +3.3V supply.

Product Features

- 26 dBm P1dB@3.3V
- 26 dB gain
- 2.5 % EVM @ P_{OUT} = 18 dBm; 54 Mbps
- 1.5 % EVM @ P_{OUT} = 18 dBm; 36 Mbps
- Single +3.3V supply voltage
- Input matched to 50 ohms
- PA power on/off logic





1 ALL DIMENSIONS ARE IN MILLIMETERS, ANGLES IN DEGREES.

2 THE TERMINAL #1 IDENTIFIER AND PAD NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012

3 LEAD COPLANARITY: 0.05 MAX.

DIMENSION APPLIES TO METALLIZED PAD AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM PAD TIP.

4x4 mm Package Outline



Advanced RFSP5032

5.15-5.85 GHz U-NII Power Amplifier

	Specification			11!4	Condition	
Parameter ¹	Min.	Тур.	Max.	Unit	Condition	
Overall						
Frequency Range	5150		5850	MHz		
Output P1dB		26		dBm		
Gain		26		dB		
Error Vector Magnitude (EVM)		2.5 1.5		% %	$P_{OUT} = +18 \text{ dBm}$; 54 Mbps data rate $P_{OUT} = +18 \text{ dBm}$; 36 Mbps data rate	
Gain Flatness		±1.0		dB	Across 200 MHz Band	
Harmonics						
2 nd Harmonic		-30		dBc	@ P1dB	
3 rd Harmonic		-30		dBc	@ P1dB	
Spurious (Stability) ²		-60		dBc/30 kHz	$P_{OUT} = -20 \text{ dBm to } P1dB$	
Reverse Isolation	50			dB		
Noise Figure		6		dB		
Input Return Loss	15			dB	With matching capacitor	
Output Return Loss	15			dB	With matching capacitor	
Power Supply						
Operating Voltage		3.3		V		
Current Consumption		180		mA	$P_{OUT} = +16 \text{ dBm}$	
		200		mA	$P_{OUT} = +18 \text{ dBm}$	
Shutdown Control						
Device On Logic High		3.3		V		
Device Off Logic Low			0.7	V		
Current Consumption			100	uA		
Turn-On Time			100	ns		
Turn-Off Time			100	ns		

Note 1: Test Conditions: $V_{CC}=3.3V$, $P_{OUT}=+18dBm$, Freq. = 5250 MHz, $T=25^{\circ}C$. Note 2: Load VSWR is set to 7:1 and the angle is varied 360 degrees.

Absolute Maximum Ratings

Parameter		Unit				
DC Power Supply	6.0	V				
DC Supply Current	800	mA				
Maximum RF input level	2	dBm				
Operating Ambient Temperature	-40 to +85	°C				
Storage Temperature	-55 to +150	°C				



The information provided herein is believed to be reliable; however, RF Solutions assumes no responsibility for inaccuracies or omissions. RF Solutions assumes no responsibility for the use of this information, and all use of such information shall be entirely at the user's own risk. Prices and specifications are subject to change without notice. No patent rights or licenses to any of the circuits described herein are implied or granted to any third party. RF Solutions does not authorize or warrant any RF Solutions product for use in life support devices and/or systems.

